



IN THE UNITED STATES PATENT AND TRADEMARK OFFICE	
<u>In re application of:</u> Ashima B. Chakravarti	<u>Filed:</u> 01/20/2004
	<u>Examiner:</u> Bradley Smith
<u>Serial No.</u> 10/707,878	<u>Group Art Unit:</u> 2891
<u>Title:</u> Polycrystalline Silicon Layer With Nano-grain Structure and Method of Manufacture	<u>Docket #:</u> FIS920030317US1

AMENDMENT

Commissioner of Patents & Trademarks
Alexandria, VA 22313

Sir:

Responsive to the Office Action of 09/27/2005, please amend the above identified application as follows: